

**SuperMOS – SOP8 -30V  $V_{DSS}$ , 9.5m $\Omega$   $R_{DS(ON)}$ , P-channel MOSFET**

**1. Description**

The ES4407 is P-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product ES4407 is Pb-free.

**2. Features**

- -30V,  $R_{DS(ON)}$ =9.5m $\Omega$ (Typ.) @ $V_{GS}$ =-10V  
 $R_{DS(ON)}$ =14m $\Omega$ (Typ.) @ $V_{GS}$ =-4.5V
- Fast Switching
- High density cell design for low  $R_{DS(on)}$
- Material : Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

**3. Applications**

- PWM applications 100% UIS TESTED
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

**4. Ordering Information**

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Sizes
ES4407	SOP8	ES4407/lot	Halogen free	Tape & Reel	3,000 PCS	UL 94V-0	13 inches

Table-1 Ordering information

**5. Pin Configuration and Functions**


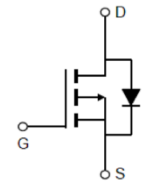
Pin	Function	Outline	Circuit Diagram
4	Gate	Note d 	
1/2/3	Source		
5/6/7/8	Drain		

Table-2 Pin configuration

## 6. Specification

### Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		$BV_{DSS}$	-30	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	V
Continuous Drain Current <sup>a</sup>	$T_A=25^\circ\text{C}$	$I_D$	-12	A
	$T_A=100^\circ\text{C}$		-10	
Maximum Power Dissipation <sup>a</sup>	$T_A=25^\circ\text{C}$	$P_D$	3.1	W
	$T_A=100^\circ\text{C}$		2.0	
Pulsed Drain Current <sup>b</sup>		$I_{DM}$	-60	A
Avalanche Current, Single Pulsed <sup>c</sup>		$I_{AS}$	-22	A
Avalanche Energy, Single Pulsed <sup>c</sup>		$E_{AS}$	72	mJ
Operating Junction Temperature		$T_J$	150	°C
Storage Temperature Range		$T_{stg}$	-55 to +150	°C

#### Thermal resistance ratings

Single Operation					
Parameter		Symbol	Typical	Maximum	Unit
Junction-to-Ambient Thermal Resistance <sup>a</sup>	$t \leq 10 \text{ s}$	$R_{\theta JA}$	32	40	°C/W
Junction-to-Case Thermal Resistance	Steady State	$R_{\theta JC}$	17	24	

Note:

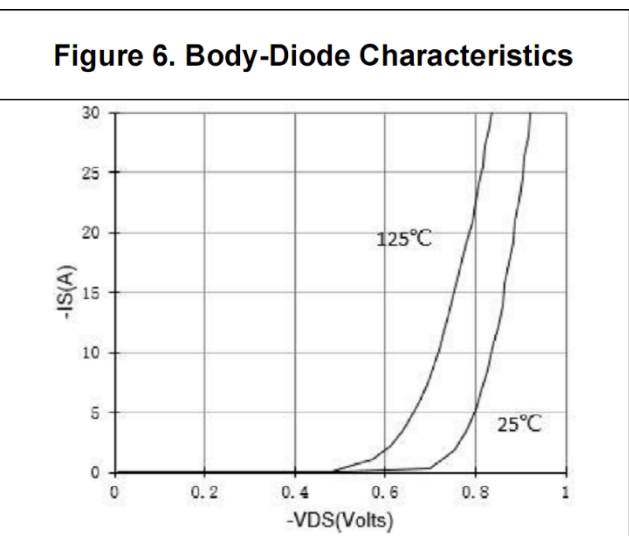
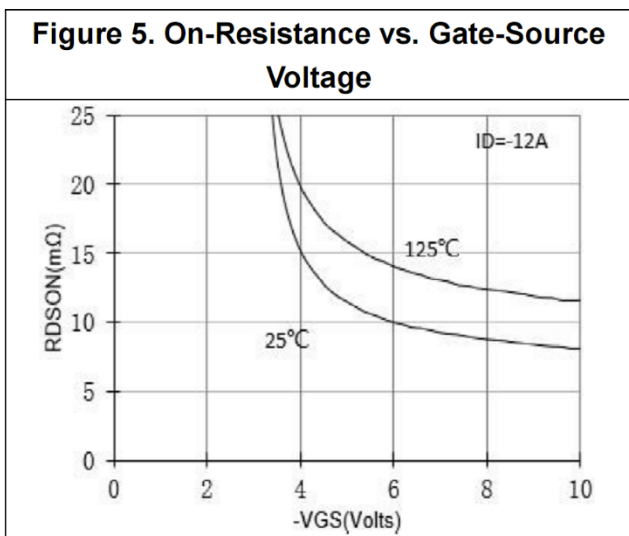
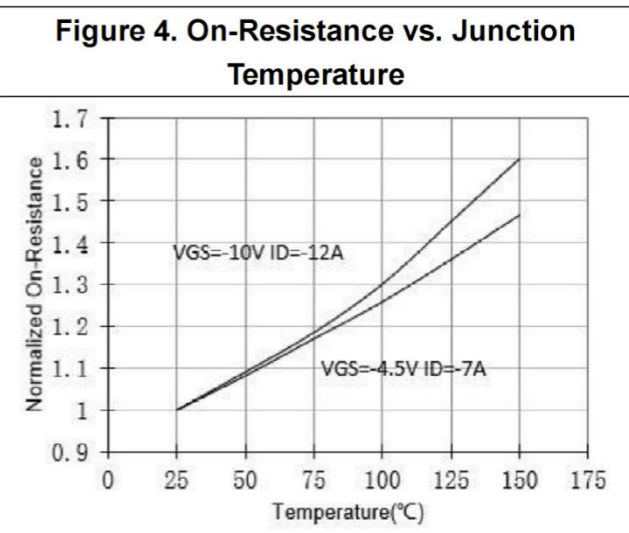
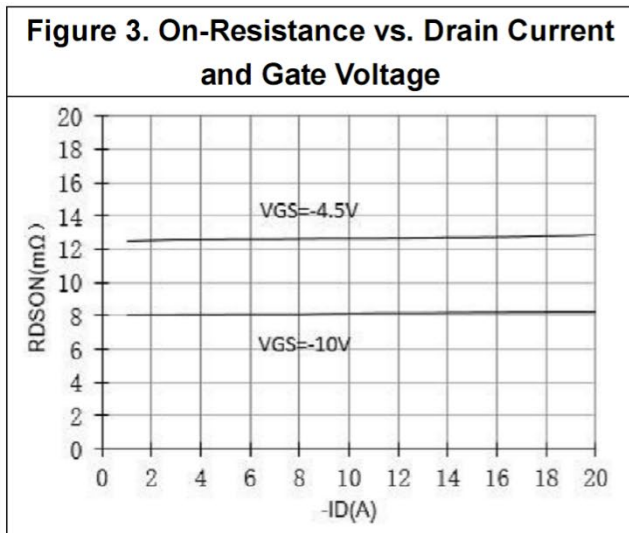
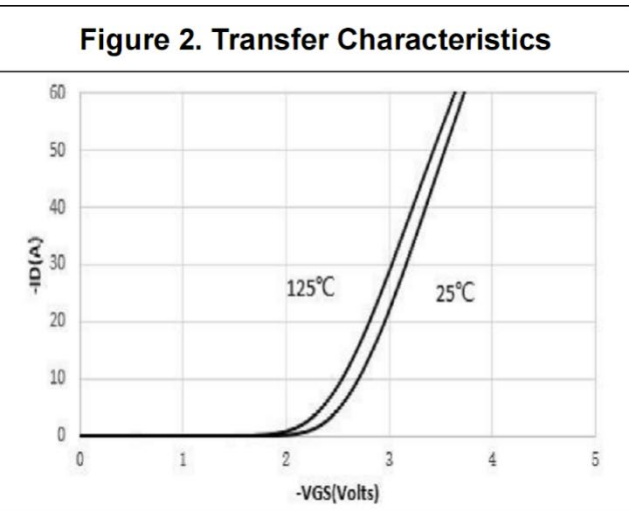
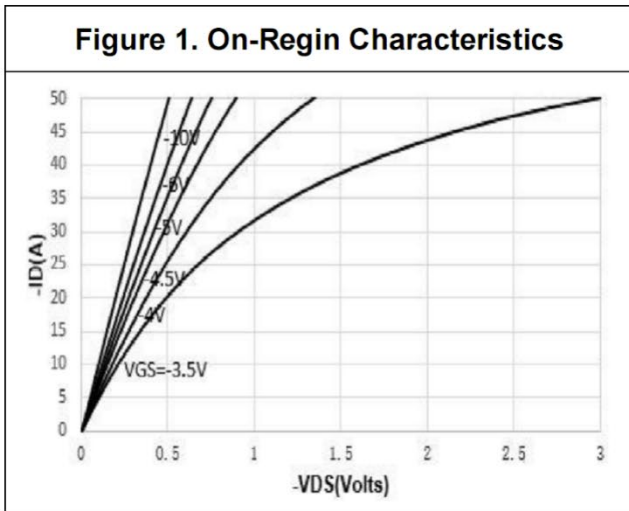
- a: Surface mounted on FR4 Board using 1 square inch pad size, 1oz copper
- b: Repetitive rating, pulse width limited by junction temperature,  $t_p=10\mu\text{s}$ , Duty Cycle=1%
- c: EAS condition:  $T_J=25^\circ\text{C}$ ,  $V_{DD}=-30\text{V}$ ,  $V_G=-10\text{V}$ ,  $L=0.3\text{mH}$ ,  $R_g=25\Omega$
- d: This diagram is only an electrical schematic, and the actual pin size is based on POD.

## Electrical Characteristics

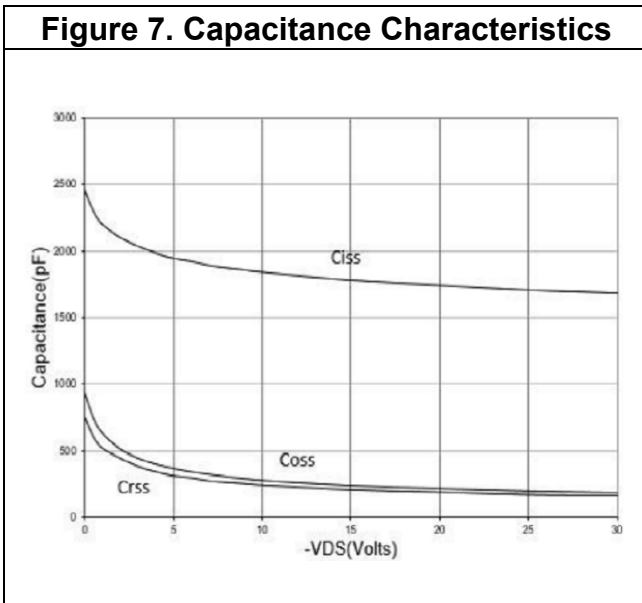
At TA = 25°C unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>OFF CHARACTERISTICS</b>						
Drain-to-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-30			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-30V, V_{GS}=0V$			-1	$\mu A$
Gate-to-source Leakage Current	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 20V$			$\pm 100$	nA
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}, I_D=-250\mu A$	-1	-1.5	-2	V
Drain-to-source On-resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-12A$		9.5	13	m $\Omega$
		$V_{GS}=-4.5V, I_D=-7A$		14	17	
Forward Trans conductance	$g_{FS}$	$V_{DS}=-5.0V, I_D=-10A$			40	S
<b>CHARGES, CAPACITANCES AND GATE RESISTANCE</b>						
Input Capacitance	$C_{ISS}$	$V_{GS}=0V, f=1MHz,$ $V_{DS}=-15V$		1780		pF
Output Capacitance	$C_{OSS}$			235		
Reverse Transfer Capacitance	$C_{RSS}$			200		
Gate Resistance	$R_g$	$f=1MHz$		6.0		$\Omega$
Total Gate Charge	$Q_{G(TOT)}$	$V_{GS}=-10V, V_{DS}=-15V,$ $I_D=-15A$		46		nC
Gate-to-Source Charge	$Q_{GS}$			1.0		
Gate-to-Drain Charge	$Q_{GD}$			1.4		
<b>SWITCHING CHARACTERISTICS</b>						
Turn-On Delay Time	$t_{d(ON)}$	$V_{GS}=-10V, V_{DS}=-15V,$ $R_L=1\Omega, R_G=3\Omega$		8		ns
Rise Time	$t_r$			27		
Turn-Off Delay Time	$t_{d(OFF)}$			68		
Fall Time	$t_f$			39		
<b>BODY DIODE CHARACTERISTICS</b>						
Forward Voltage	$V_{SD}$	$V_{GS}=0V, I_S=-1.0A$		-0.7	-1	V

7. Typical Characteristic

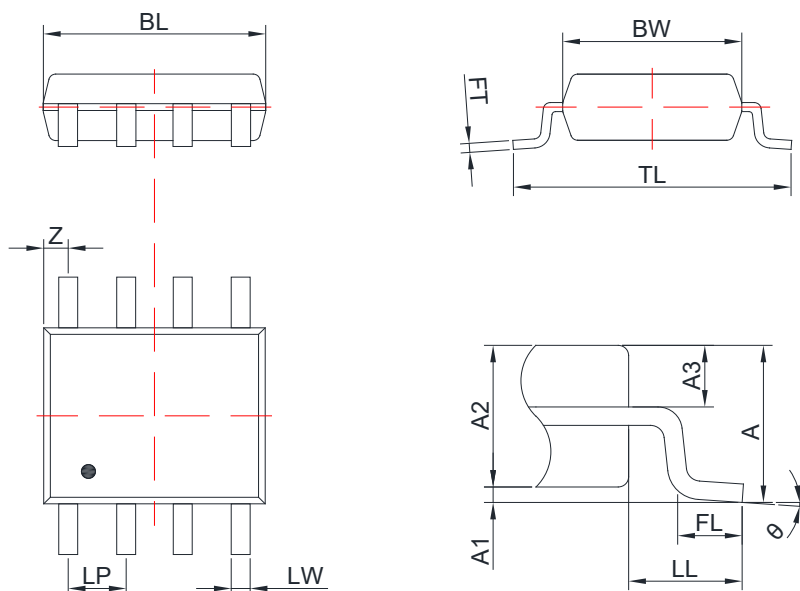


**Figure 7. Capacitance Characteristics**



8. Dimension (SOP8)

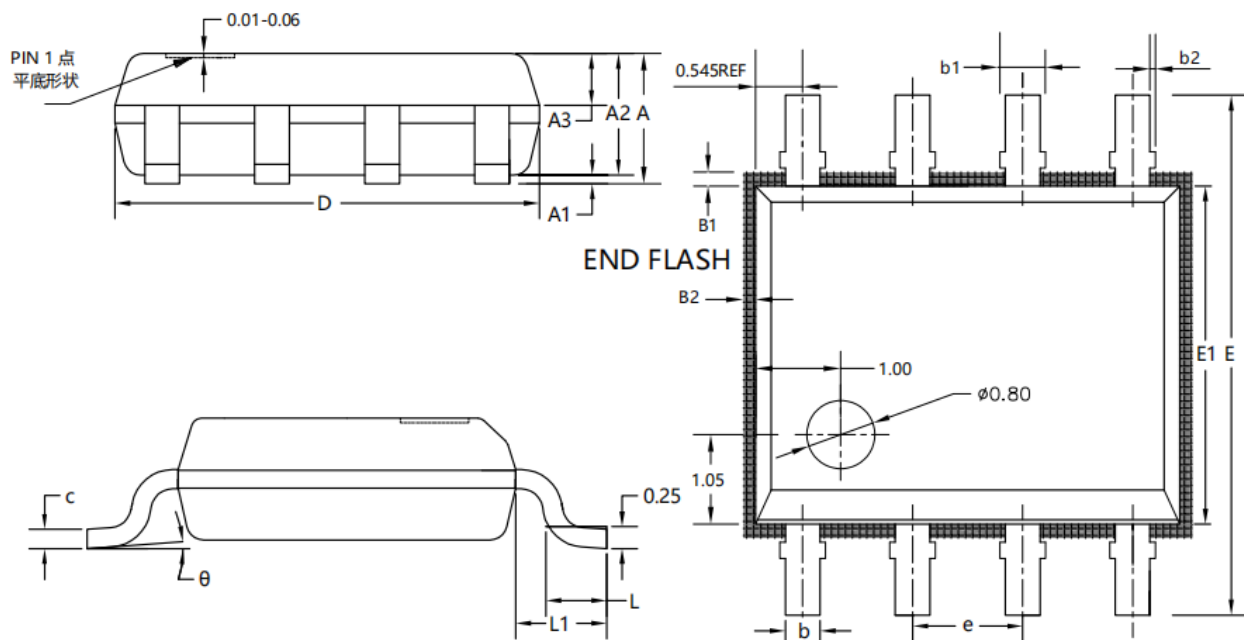
POD A(Y)



COMMON DIMENSIONS: UNITS OF MEASURE=MILLIMETER

Symbol	Dimensions		Symbol	Dimensions	
	Min.	Max.		Min.	Max.
A	1.75		FL	0.50	0.80
A1	0.05	0.15	LP	1.25	1.30
A2	1.40	1.50	LL	1.1 BSC	
A3	0.623 BSC		LW	0.38	0.43
BL	4.92	5.08	TL	5.90	6.10
BW	3.70	4.10	Z	0.54	
FT	0.20	0.21	theta	0°	8°

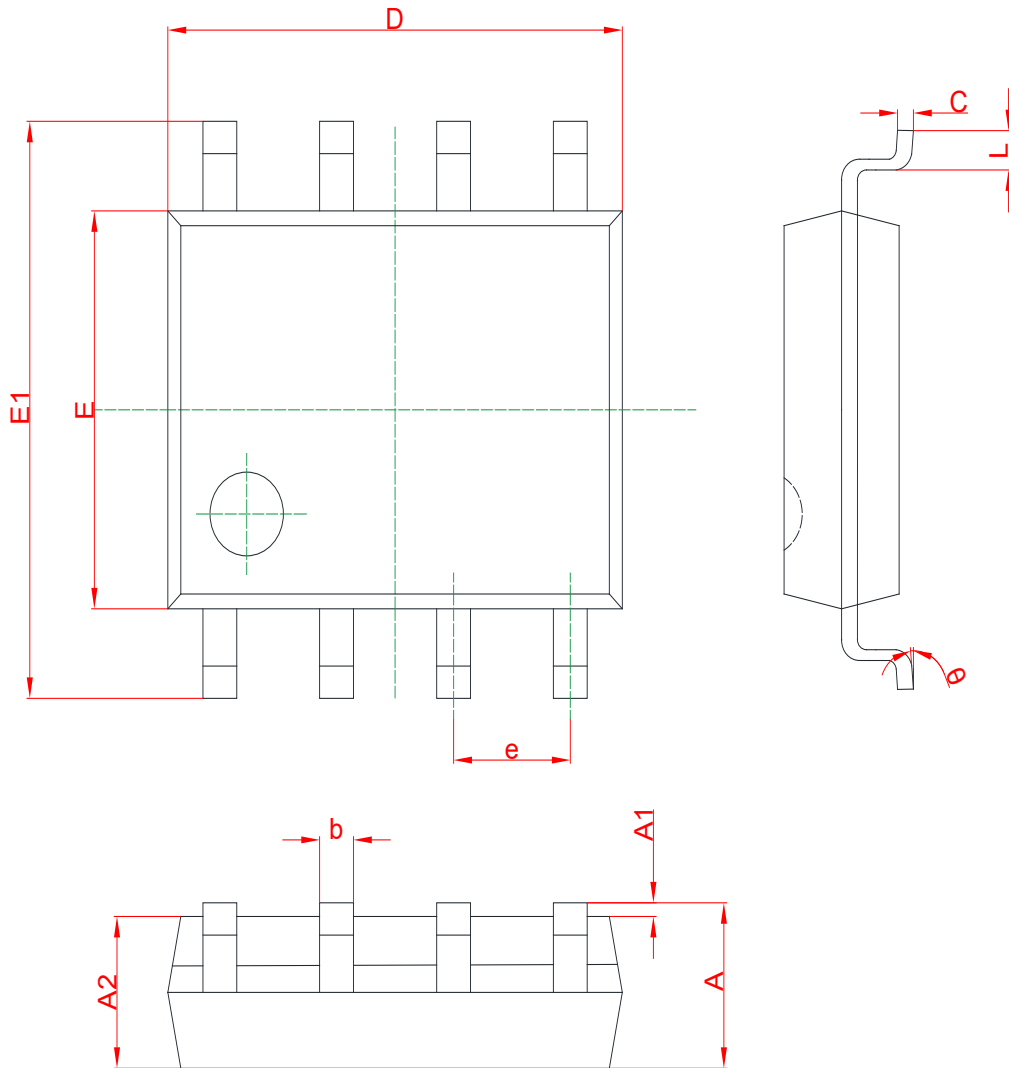
POD B(C)



COMMON DIMENSIONS: UNITS OF MEASURE=MILLIMETER

Symbol	Dimensions			Symbol	Dimensions		
	Min.	NOM.	Max.		Min.	NOM.	Max.
A	1.55	1.65	1.75	L	0.50	0.60	0.70
A1	0.06	0.11	0.16	L1	0.90	1.05	1.20
A2	1.35	1.45	1.55	θ	0°	4°	8°
A3	0.60	0.70	0.80	B1	0.14MAX		
b	0.30	0.40	0.50	B2	0.12MAX		
c	0.17	0.20	0.25	b1	0.66MAX		
D	4.80	4.90	5.00	b2	0	0.04	0.08
E	5.80	6.00	6.20	e	1.27BSC		
E1	3.80	3.90	4.00				

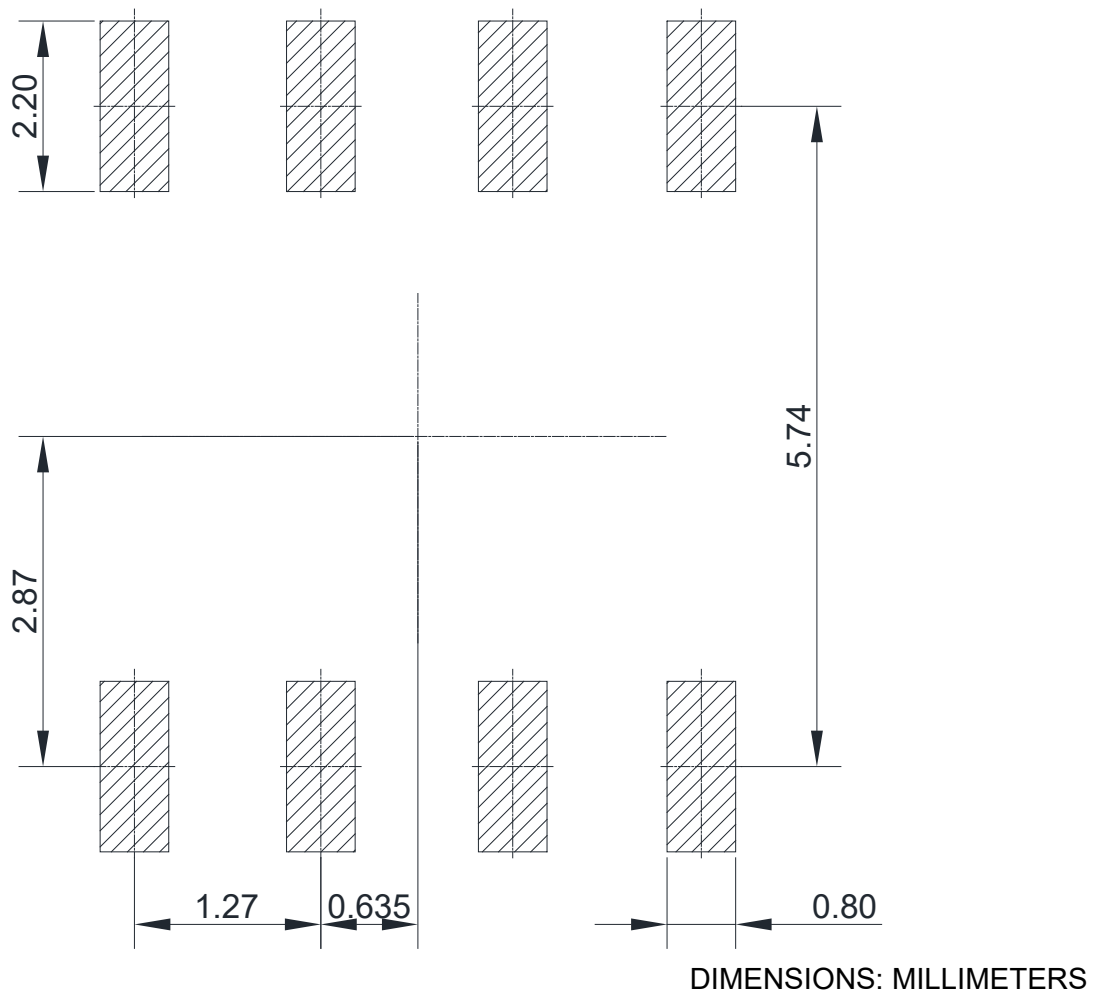
POD C(X)



Symbol	Dimensions		Symbol	Dimensions	
	Min.	Max.		Min.	Max.
L	0.40	0.60	e	1.27 TYP	
D	4.95	5.05	c	0.15	0.25
E	3.8	4.0	A2	1.33	1.50
E1	5.80	6.20	A1	0.04	0.20
b	0.4 TYP		θ	0°	8°



## 9. Recommended Soldering Footprint



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